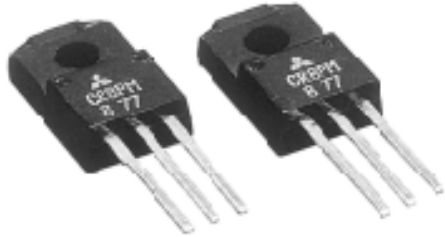


CR8PM

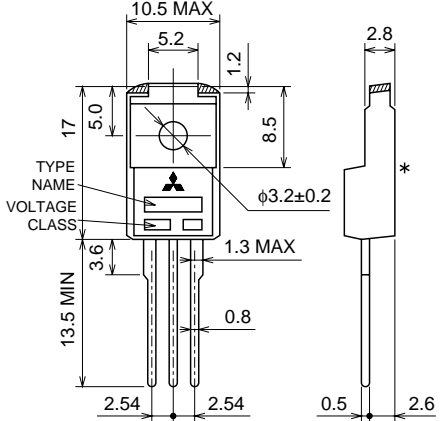
MEDIUM POWER USE
INSULATED TYPE, GLASS PASSIVATION TYPE

CR8PM



- I_T (AV) 8A
- V_{DRM} 400V/600V
- I_{GT} 15mA
- V_{iso} 1500V
- UL Recognized: File No. E80276

OUTLINE DRAWING Dimensions in mm



① CATHODE
② ANODE
③ GATE

TO-220F

* Measurement point of case temperature

APPLICATION

Switching mode power supply, ECR, regulator for auticycle, motor control

MAXIMUM RATINGS (Ta=25°C, unless otherwise noted)

Symbol	Parameter	Voltage class		Unit
		8	12	
VRRM	Repetitive peak reverse voltage	400	600	V
VRSM	Non-repetitive peak reverse voltage	500	720	V
VR (DC)	DC reverse voltage	320	480	V
VDRM	Repetitive peak off-state voltage	400	600	V
VD (DC)	DC off-state voltage	320	480	V

Symbol	Parameter	Conditions	Ratings	Unit
I_T (RMS)	RMS on-state current		12.6	A
I_T (AV)	Average on-state current	Commercial frequency, sine half wave, 180° conduction, Tc=81°C	8.0	A
I_{TSM}	Surge on-state current	60Hz sine half wave 1 full cycle, peak value, non-repetitive	120	A
I^2t	I^2t for fusing	Value corresponding to 1 cycle of half wave 60Hz, surge on-state current	60	A ² s
PGM	Peak gate power dissipation		5.0	W
PG (AV)	Average gate power dissipation		0.5	W
VFGM	Peak gate forward voltage		6.0	V
VRGM	Peak gate reverse voltage		10	V
IFGM	Peak gate forward current		2.0	A
Tj	Junction temperature		-40 ~ +125	°C
Tstg	Storage temperature		-40 ~ +125	°C
—	Weight	Typical value	2.0	g
Viso	Isolation voltage	Ta=25°C, AC 1 minute, each terminal to case	1500	V

CR8PM

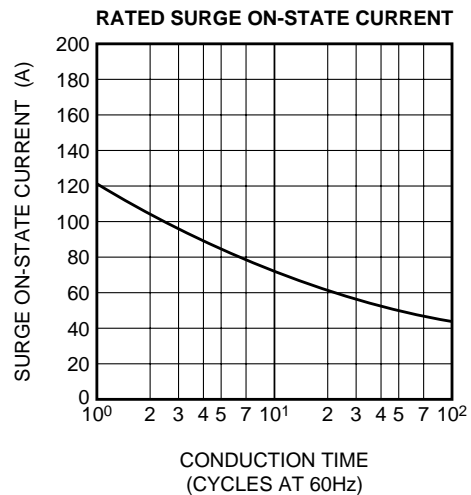
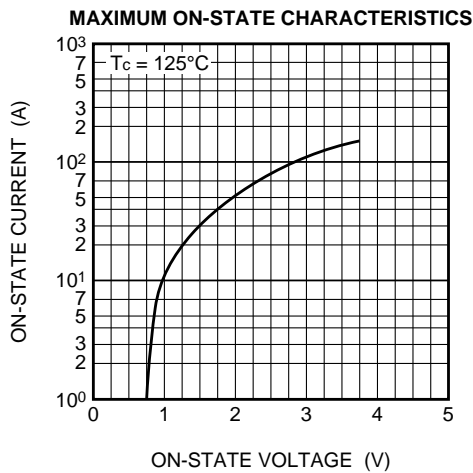
MEDIUM POWER USE
INSULATED TYPE, GLASS PASSIVATION TYPE

ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
IRRM	Repetitive peak reverse current	$T_j=125^\circ\text{C}$, V_{RRM} applied	—	—	2.0	mA
IDRM	Repetitive peak off-state current	$T_j=125^\circ\text{C}$, V_{DRM} applied	—	—	2.0	mA
V _{TM}	On-state voltage	$T_c=25^\circ\text{C}$, $I_{TM}=25\text{A}$, instantaneous value	—	—	1.4	V
V _{GT}	Gate trigger voltage	$T_a=25^\circ\text{C}$, $V_D=6\text{V}$, $I_T=1\text{A}$	—	—	1.0	V
V _{GD}	Gate non-trigger voltage	$T_j=125^\circ\text{C}$, $V_D=1/2V_{DRM}$	0.2	—	—	V
I _{GT}	Gate trigger current	$T_j=25^\circ\text{C}$, $V_D=6\text{V}$, $I_T=1\text{A}$	—	—	15	mA
I _H	Holding current	$T_j=25^\circ\text{C}$, $V_D=12\text{V}$	—	1.5	—	mA
R _{th(j-c)}	Thermal resistance	Junction to case *1	—	—	3.7	$^\circ\text{C}/\text{W}$

*1. The contact thermal resistance R_{th(j-c)} is 0.5 $^\circ\text{C}/\text{W}$ with greased.

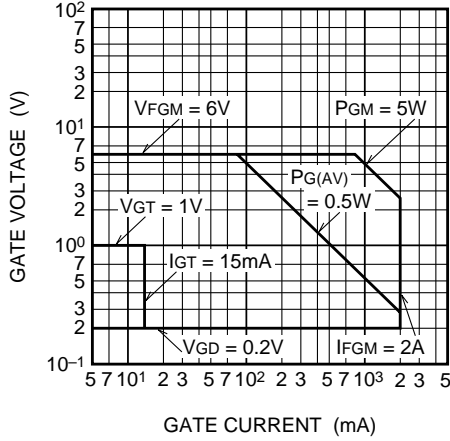
PERFORMANCE CURVES



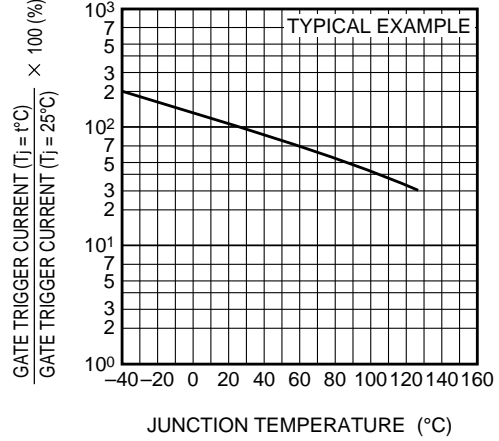
CR8PM

MEDIUM POWER USE
INSULATED TYPE, GLASS PASSIVATION TYPE

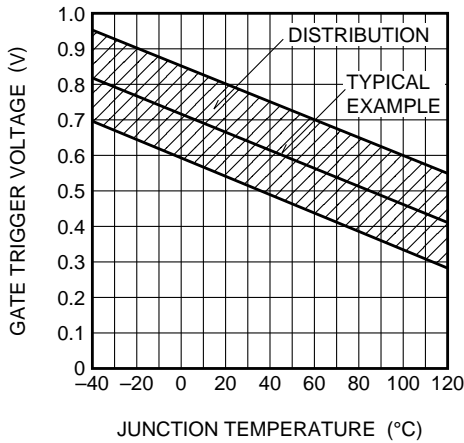
GATE CHARACTERISTICS



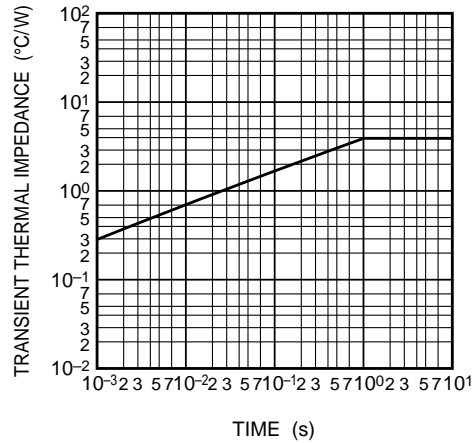
GATE TRIGGER CURRENT VS. JUNCTION TEMPERATURE



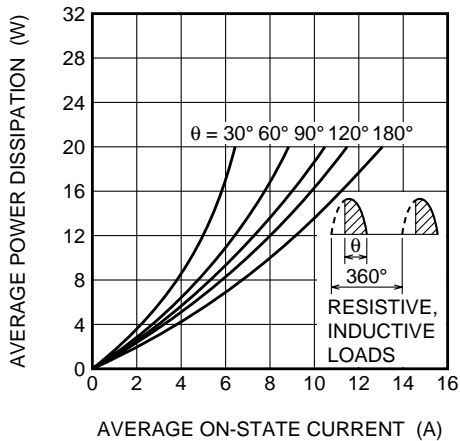
GATE TRIGGER VOLTAGE VS. JUNCTION TEMPERATURE



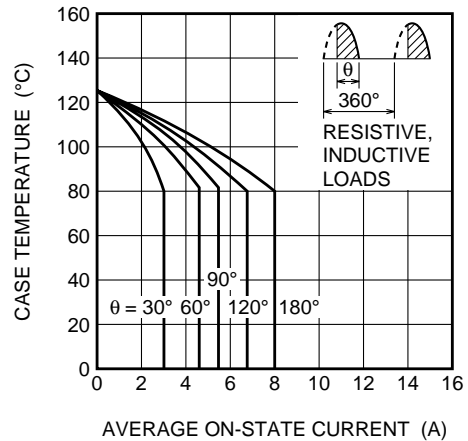
MAXIMUM TRANSIENT THERMAL IMPEDANCE CHARACTERISTICS (JUNCTION TO CASE)



MAXIMUM AVERAGE POWER DISSIPATION (SINGLE-PHASE HALF WAVE)



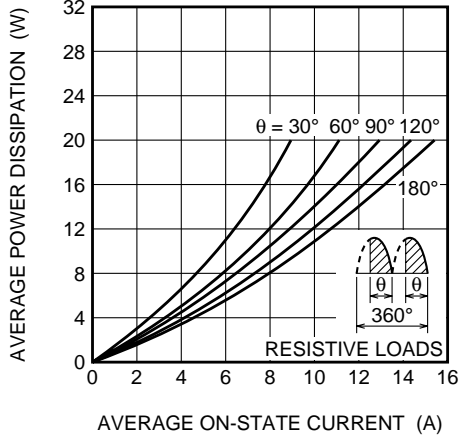
ALLOWABLE CASE TEMPERATURE VS. AVERAGE ON-STATE CURRENT (SINGLE-PHASE HALF WAVE)



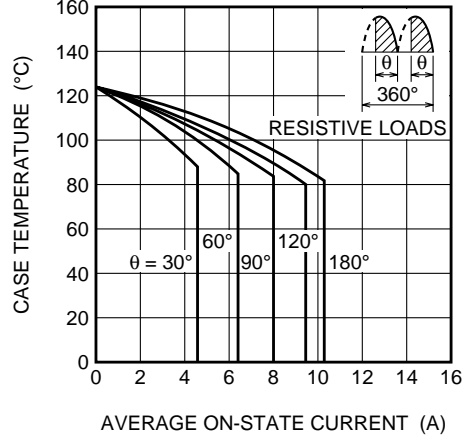
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MEDIUM POWER USE
INSULATED TYPE, GLASS PASSIVATION TYPE

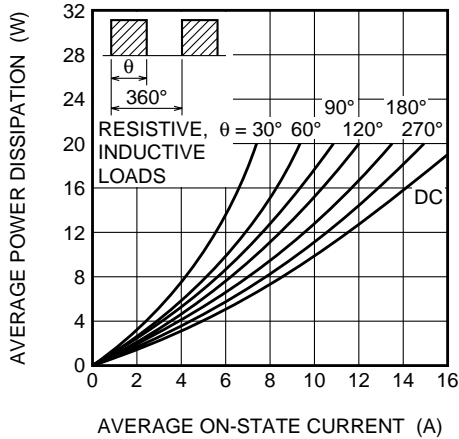
**MAXIMUM AVERAGE POWER DISSIPATION
(SINGLE-PHASE FULL WAVE)**



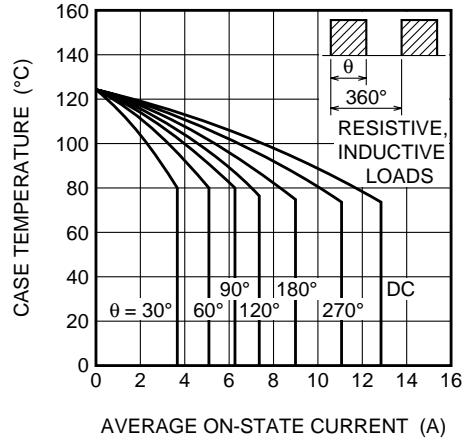
**ALLOWABLE CASE TEMPERATURE VS.
AVERAGE ON-STATE CURRENT
(SINGLE-PHASE FULL WAVE)**



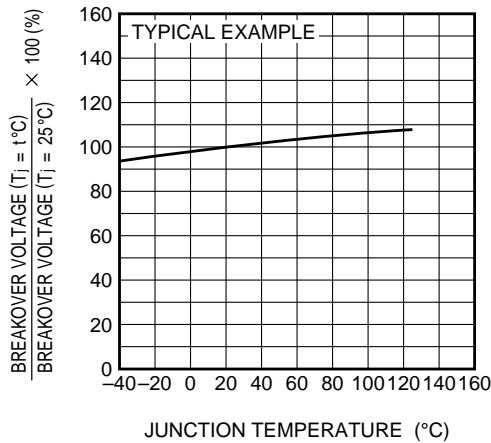
**MAXIMUM AVERAGE POWER DISSIPATION
(RECTANGULAR WAVE)**



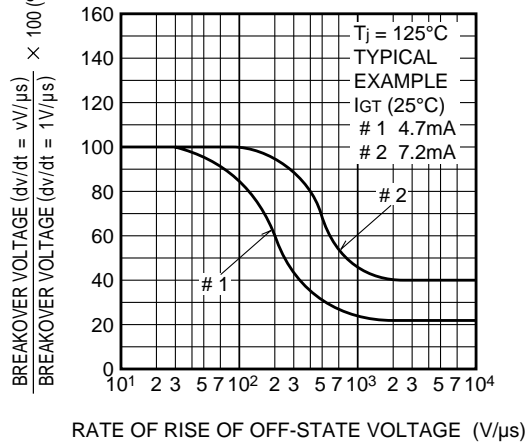
**ALLOWABLE CASE TEMPERATURE VS.
AVERAGE ON-STATE CURRENT
(RECTANGULAR WAVE)**



**BREAKOVER VOLTAGE VS.
JUNCTION TEMPERATURE**



**BREAKOVER VOLTAGE VS.
RATE OF RISE OF OFF-STATE VOLTAGE**

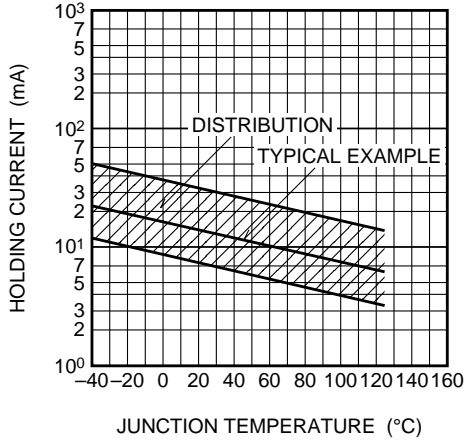


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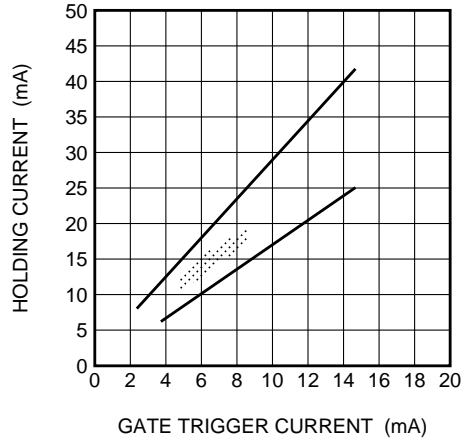
MEDIUM POWER USE

INSULATED TYPE, GLASS PASSIVATION TYPE

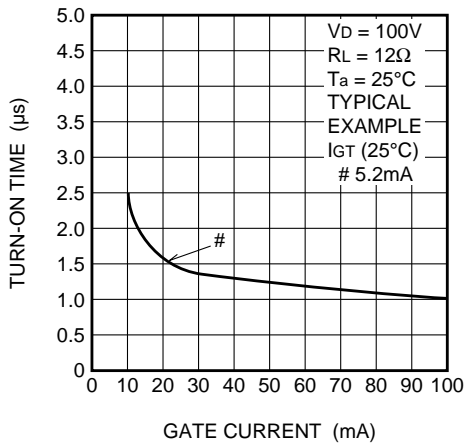
HOLDING CURRENT VS. JUNCTION TEMPERATURE



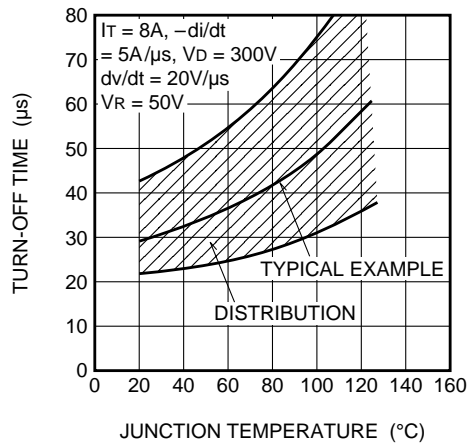
HOLDING CURRENT VS. GATE TRIGGER CURRENT



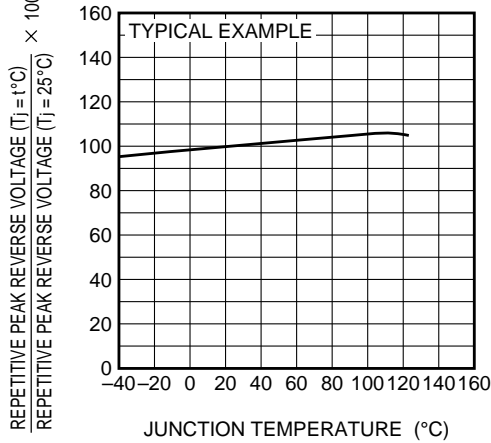
TURN-ON TIME VS. GATE CURRENT



TURN-OFF TIME VS. JUNCTION TEMPERATURE



REPETITIVE PEAK REVERSE VOLTAGE VS. JUNCTION TEMPERATURE



GATE TRIGGER CURRENT VS. GATE CURRENT PULSE WIDTH

